

Product specification Supersedes data of 1997 Feb 03 IC24 Data Handbook 1998 Apr 20





74LV14

### **FEATURES**

- Wide operating voltage: 1.0 to 5.5 V
- Optimized for Low Voltage applications: 1.0 to 3.6 V
- Accepts TTL input levels between  $V_{CC}$  = 2.7 V and  $V_{CC}$  = 3.6 V
- Typical V<sub>OLP</sub> (output ground bounce) < 0.8 V at V<sub>CC</sub> = 3.3 V,  $T_{amb} = 25^{\circ}C.$
- Typical V<sub>OHV</sub> (output V<sub>OH</sub> undershoot) > 2 V at V<sub>CC</sub> = 3.3 V,  $T_{amb} = 25^{\circ}C.$
- Output capability: standard
- I<sub>CC</sub> category: SSI

### QUICK REFERENCE DATA

GND = 0 V;  $T_{amb} = 25^{\circ}C$ ;  $t_r = t_f \le 2.5 \text{ ns}$ 

### **APPLICATIONS**

· Wave and pulse shapers for highly noisy environments

### DESCRIPTION

The 74LV14 is a low-voltage Si-gate CMOS device and is pin and function compatible with 74HC/HCT14.

The 74LV14 provides six inverting buffers with Schmitt-trigger action. It is capable of transforming slowly changing input signals into sharply defined, jitter-free output signals.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t <sub>PHL</sub> /t <sub>PLH</sub>	Propagation delay nA to nY	C <sub>L</sub> = 15 pF; V <sub>CC</sub> = 3.3 V	13	ns
CI	Input capacitance		3.5	pF
C <sub>PD</sub>	Power dissipation capacitance per gate	See Notes 1 and 2	15	pF

NOTES:

1. C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in  $\mu$ W) P<sub>D</sub> = C<sub>PD</sub> × V<sub>CC</sub><sup>2</sup> × f<sub>i</sub> +  $\sum$  (C<sub>L</sub> × V<sub>CC</sub><sup>2</sup> × f<sub>o</sub>) where: f<sub>i</sub> = input frequency in MHz; C<sub>L</sub> = output load capacitance in pF; f<sub>o</sub> = output frequency in MHz; V<sub>CC</sub> = supply voltage in V;  $\sum_{i=1}^{N} (C_L \times V_{CC}^2 \times f_0) = \text{sum of the outputs.}$ 2. The condition is V<sub>1</sub> = GND to V<sub>CC.</sub>

### **ORDERING INFORMATION**

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG. DWG. #
14-Pin Plastic DIL	–40°C to +125°C	74LV14 N	74LV14 N	SOT27-1
14-Pin Plastic SO	-40°C to +125°C	74LV14 D	74LV14 D	SOT108-1
14-Pin Plastic SSOP Type II	-40°C to +125°C	74LV14 DB	74LV14 DB	SOT337-1
14-Pin Plastic TSSOP Type I	-40°C to +125°C	74LV14 PW	74LV14PW DH	SOT402-1

### **PIN DESCRIPTION**

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 3, 5, 9, 11, 13	1A – 6A	Data inputs
2, 4, 6, 8, 10, 12	1Y – 6Y	Data outputs
7	GND	Ground (0 V)
14	V <sub>CC</sub>	Positive supply voltage

### **FUNCTION TABLE**

INPUT	OUTPUT nY				
nA					
L	Н				
н	L				

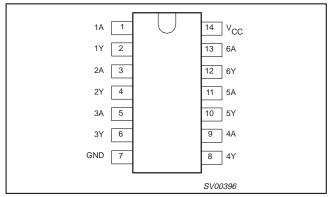
NOTES:

H = HIGH voltage level

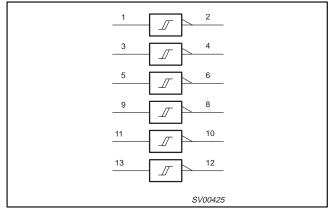
L = LOW voltage level

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### **PIN CONFIGURATION**



### LOGIC SYMBOL (IEEE/IEC)



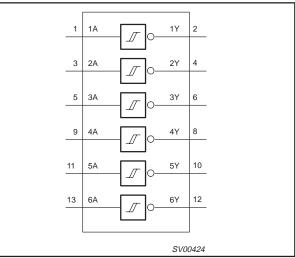
### **RECOMMENDED OPERATING CONDITIONS**

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
V <sub>CC</sub>	DC supply voltage	See Note1	1.0	3.3	5.5	V
VI	Input voltage		0	-	V <sub>CC</sub>	V
Vo	Output voltage		0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	Operating ambient temperature range in free air	See DC and AC characteristics	-40 -40		+85 +125	°C

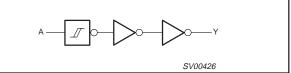
NOTE:

1. The LV is guaranteed to function down to  $V_{CC}$  = 1.0V (input levels GND or  $V_{CC}$ ); DC characteristics are guaranteed from  $V_{CC}$  = 1.2V to  $V_{CC}$  = 5.5V.

### LOGIC SYMBOL



### LOGIC DIAGRAM



74LV14

### ABSOLUTE MAXIMUM RATINGS<sup>1, 2</sup>

In accordance with the Absolute Maximum Rating System (IEC 134). Voltages are referenced to GND (ground = 0V).

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V <sub>CC</sub>	DC supply voltage		-0.5 to +7.0	V
$\pm I_{\text{IK}}$	DC input diode current	$V_{I} < -0.5 \text{ or } V_{I} > V_{CC} + 0.5 V$	20	mA
$\pm I_{OK}$	DC output diode current	$V_{\rm O}$ < -0.5 or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5V	50	mA
$\pm I_{O}$	DC output source or sink current – standard outputs	$-0.5V < V_{O} < V_{CC} + 0.5V$	25	mA
$\substack{\pm  I_{GND}, \\ \pm  I_{CC}}$	DC V <sub>CC</sub> or GND current for types with – standard outputs		50	mA
T <sub>stg</sub>	Storage temperature range		-65 to +150	°C
P <sub>TOT</sub>	Power dissipation per package – plastic DIL – plastic mini-pack (SO) – plastic shrink mini-pack (SSOP and TSSOP)	for temperature range: -40 to +125°C above +70°C derate linearly with 12 mW/K above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	750 500 400	mW

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

### DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions. Voltages are referenced to GND (ground = 0V).

					LIMITS				
SYMBOL	PARAMETER	TEST CONDITIONS	-4	0°C to +8	5°C	-40°C to	o +125°C	UNIT	
			MIN	TYP <sup>1</sup>	MAX	MIN	MAX	1	
		$V_{CC}$ = 1.2V; $V_I$ = $V_{IH}$ or $V_{IL;}$ – $I_O$ = 100 $\mu$ A		1.2					
		$V_{CC}$ = 2.0V; $V_I$ = $V_{IH}$ or $V_{IL;}$ – $I_O$ = 100 $\mu$ A	1.8	2.0		1.8			
V <sub>OH</sub>	V <sub>OH</sub> HIGH level output voltage; all outputs	$V_{CC}$ = 2.7V; $V_I$ = $V_{IH}$ or $V_{IL;}$ – $I_O$ = 100 $\mu$ A	2.5	2.7		2.5		V	
		$V_{CC}$ = 3.0V; $V_I$ = $V_{IH}$ or $V_{IL;}$ – $I_O$ = 100 $\mu$ A	2.8	3.0		2.8			
		$V_{CC}$ = 4.5V; $V_I$ = $V_{IH}$ or $V_{IL;}$ – $I_O$ = 100 $\mu$ A	4.3	4.5		4.3			
V <sub>OH</sub> volta STA	HIGH level output voltage;	$V_{CC}$ = 3.0V; $V_{I}$ = $V_{IH}$ or $V_{IL;}$ – $I_{O}$ = 6mA	2.40	2.82		2.20		v	
	STANDARD outputs	$V_{CC}$ = 4.5V; $V_{I}$ = $V_{IH}$ or $V_{IL;}$ –I_O = 12mA	3.60	4.20		3.50		Ĵ	
		$V_{CC}$ = 1.2V; $V_I$ = $V_{IH}$ or $V_{IL}$ ; $I_O$ = 100 $\mu$ A		0					
	LOW level output	$V_{CC}$ = 2.0V; $V_I$ = $V_{IH}$ or $V_{IL}$ ; $I_O$ = 100 $\mu$ A		0	0.2		0.2		
V <sub>OL</sub>	voltage; all outputs	$V_{CC}$ = 2.7V; $V_I$ = $V_{IH}$ or $V_{IL}$ ; $I_O$ = 100 $\mu$ A		0	0.2		0.2	V	
		$V_{CC}$ = 3.0V; $V_I$ = $V_{IH}$ or $V_{IL}$ ; $I_O$ = 100 $\mu$ A		0	0.2		0.2		
		$V_{CC}$ = 4.5V; $V_I$ = $V_{IH}$ or $V_{IL}$ ; $I_O$ = 100 $\mu$ A		0	0.2		0.2		
Vol	LOW level output voltage;	$V_{CC}$ = 3.0V; $V_{I}$ = $V_{IH}$ or $V_{IL;}$ $I_{O}$ = 6mA		0.25	0.40		0.50	v	
VOL	STANDARD outputs	$V_{CC}$ = 4.5V; $V_{I}$ = $V_{IH}$ or $V_{IL;}$ $I_{O}$ = 12mA		0.35	0.55		0.65	Ì	
lı	Input leakage current	$V_{CC}$ = 5.5V; $V_{I}$ = $V_{CC}$ or GND			1.0		1.0	μA	
I <sub>CC</sub>	Quiescent supply current; SSI	$V_{CC} = 5.5V; V_I = V_{CC} \text{ or GND}; I_O = 0$			20.0		40	μΑ	
$\Delta I_{CC}$	Additional quiescent supply current	$V_{CC} = 2.7V$ to 3.6V; $V_{I} = V_{CC} - 0.6V$			500		850	μΑ	

NOTE:

1. All typical values are measured at  $T_{amb} = 25^{\circ}C$ .

### **TRANSFER CHARACTERISTICS**

Voltages are referenced to GND (ground = 0 V)

				T <sub>amb</sub> (°C)				Т	EST CONDITIONS		
SYMBOL	PARAMETER		–40 TO +85		–40 TC	) +125	UNIT	V <sub>CC</sub>	WAVEFORMS		
		MIN.	TYP.	MAX.	MIN.	MIN.	1	(Ŭ)	WAVEFORMS		
		-	0.70	-	-	_		1.2			
		0.8	1.10	1.4	0.8	1.4		2.0			
		1.0	1.45	2.0	1.0	2.0		2.7			
V <sub>T+</sub> Positive-g threshold	Positive-going	1.2	1.60	2.2	1.2	2.2	V	3.0	Figure 1 and 2		
	theshold	1.5	1.95	2.4	1.5	2.4		3.6			
		1.7	2.50	3.15	1.7	3.15		4.5			
		2.1	3.00	3.85	2.1	3.85		5.5			
		-	0.34	-	-	-		1.2			
		0.3	0.65	0.9	0.3	0.9		2.0			
		0.4	0.90	1.4	0.4	1.4		2.7			
$V_{T-}$	Negative-going threshold	0.6	1.05	1.5	0.6	1.5	V	3.0	Figure 1 and 2		
		0.8	1.30	1.8	0.8	1.8		3.6			
		0.9	1.60	2.0	0.9	2.0		4.5			
		1.1	2.00	2.6	1.1	2.6		5.5			
		-	0.30	-	-	-		1.2			
		0.2	0.55	0.8	0.2	0.8		2.0			
		0.3	0.60	1.1	0.3	1.1		2.7			
$V_{H}$	Hysteresis (V <sub>T+</sub> – V <sub>T-</sub> )	0.4	0.65	1.2	0.4	1.2	V	3.0	Figure 1 and 2		
	(*1+ *1-)	0.4	0.70	1.2	0.4	1.2		3.6			
		0.4	0.80	1.4	0.4	1.4		4.5			
		0.6	1.00	1.5	0.6	1.5		5.5			

#### NOTES:

1. All typical values are measured at  $T_{amb} = 25^{\circ}C$ 2. The V<sub>IH</sub> and V<sub>IL</sub> from the DC family characteristics are superseded by the V<sub>T+</sub> and V<sub>T-</sub>.

### **AC CHARACTERISTICS**

 $GND = 0V; \ t_r \leq t_f = 2.5ns; \ C_L = 50pF; \ R_L = 1K\Omega$ 

			CONDITION		LIMITS					
SYMBOL	PARAMETER	WAVEFORM	CONDITION		40 to +85 °	С	<b>−40 to +125</b> °C		UNIT	
			V <sub>CC</sub> (V)	MIN	TYP <sup>1</sup>	MAX	MIN	MAX		
		n delay Figure 6	1.2		80					
				2.0		27	37		48	
t <sub>PHL/PLH</sub>	Propagation delay nA to nY		2.7		20	28		35	ns	
			3.0 to 3.6		15 <sup>2</sup>	22		28		
			4.5 to 5.5			18		23		

NOTES:

1. Unless otherwise stated, all typical values are measured at  $T_{amb} = 25^{\circ}C$ 2. Typical values are measured at  $V_{CC} = 3.3 \text{ V}$ .

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## TRANSFER CHARACTERISTIC WAVEFORMS

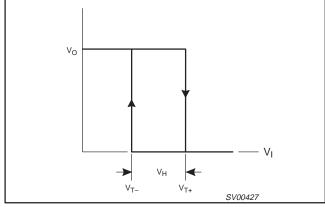


Figure 1. Transfer characteristic.

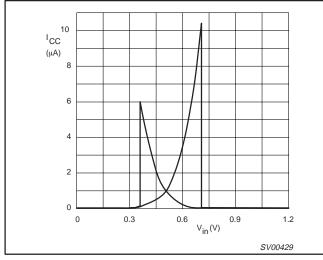


Figure 3. Typical 74LV14 transfer characteristics;  $V_{CC} = 1.2V$ .

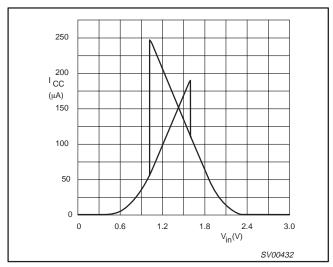


Figure 5. Typical 74LV14 transfer characteristics; V<sub>CC</sub> = 3.0V.

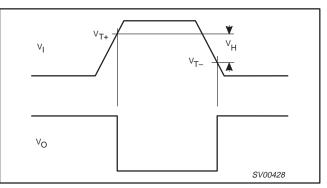


Figure 2. Definition of  $v_{T\,+}\,,$   $V_{T\!-}$  and  $V_{H};$  where  $V_{T\!+}$  and  $V_{T\!-}$  are between limits of 20% and 70%

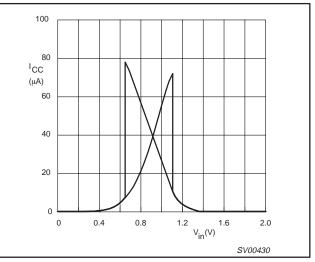


Figure 4. Typical 74LV14 transfer characteristics; V<sub>CC</sub> = 2.0V.

### AC WAVEFORMS

 $V_M$  = 1.5 V at  $V_{CC}$   $\geq$  2.7 V;  $V_M$  = 0.5  $\times$   $V_{CC}$  at  $V_{CC}$  < 2.7 V  $V_{OL}$  and  $V_{OH}$  are the typical output voltage drop that occur with the output load.

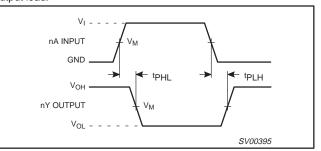


Figure 6. Input (nA) to output (nY) propagation delays.

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### **APPLICATION INFORMATION**

The slow input rise and fall times cause additional power dissipation, this can be calculated using the following formula:

$$\mathsf{P}_{ad} = \mathsf{f}_i \times (\mathsf{t}_r \times \mathsf{I}_{\mathsf{CCa}} + \mathsf{t}_f \times \mathsf{I}_{\mathsf{CCa}}) \times \mathsf{V}_{\mathsf{CC}}.$$

#### Where:

 $P_{ad}$  = additional power dissipation ( $\mu$ W)

- f<sub>i</sub> = input frequency (MHz)
- $t_r$  = input rise time (ns); 10% 90%
- $t_f$  = input fall time (ns); 10% 90%
- $I_{CCa}$  = average additional supply current (µA)

Average  $I_{CC_a}$  differs with positive or negative input transitions, as shown in Figure 7.

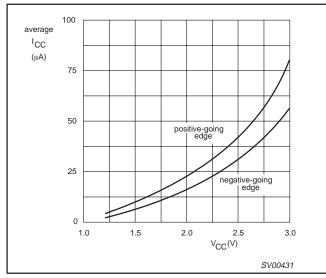


Figure 7. Average I<sub>CC</sub> for LV Schmitt-trigger devices; linear change of V<sub>I</sub> between 0.1 V<sub>CC</sub> to 0.9 V<sub>CC</sub>.

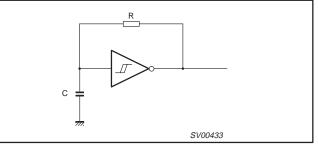
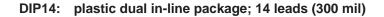


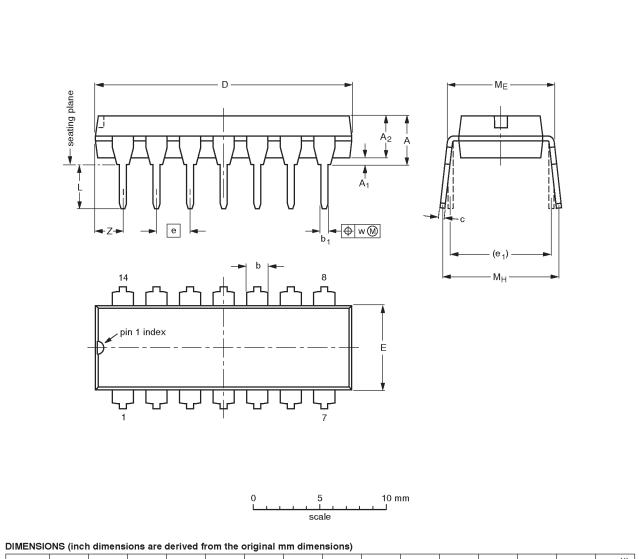
Figure 8. Relaxation oscillator using the LV14.

#### Note to application information:

All values given are typical unless otherwise specified. Note to Figure 8

$$f = \frac{1}{T} \approx \frac{1}{0.8 \times RC}$$





UNIT	A max.	A <sub>1</sub> min.	A <sub>2</sub> max.	b	b <sub>1</sub>	с	D <sup>(1)</sup>	E <sup>(1)</sup>	e	e <sub>1</sub>	L	ME	M <sub>H</sub>	w	Z <sup>(1)</sup> max.
mm	4.2	0.51	3.2	1.73 1.13	0.53 0.38	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.2
inches	0.17	0.020	0.13	0.068 0.044	0.021 0.015	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.087

#### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

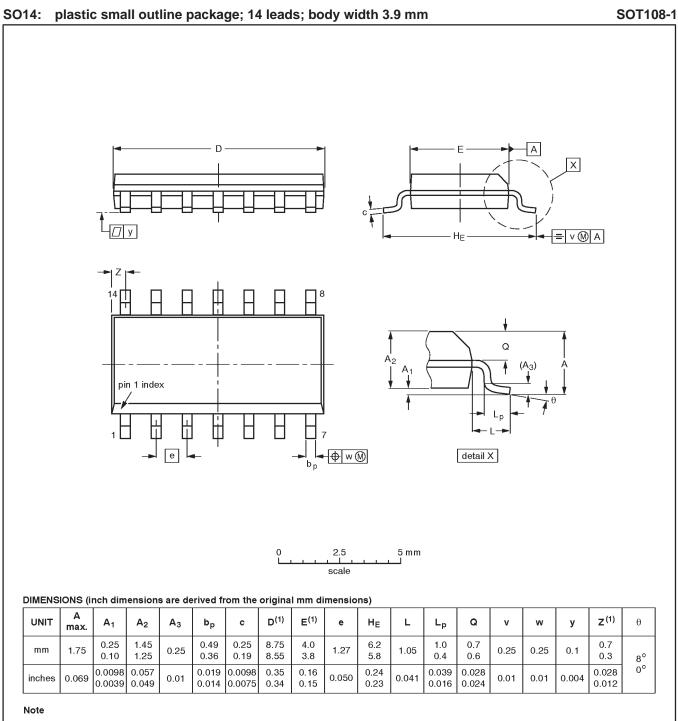
OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT27-1	050G04	MO-001AA				<del>-92-11-17</del> 95-03-11	

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# Product specification 74LV14

SOT27-1

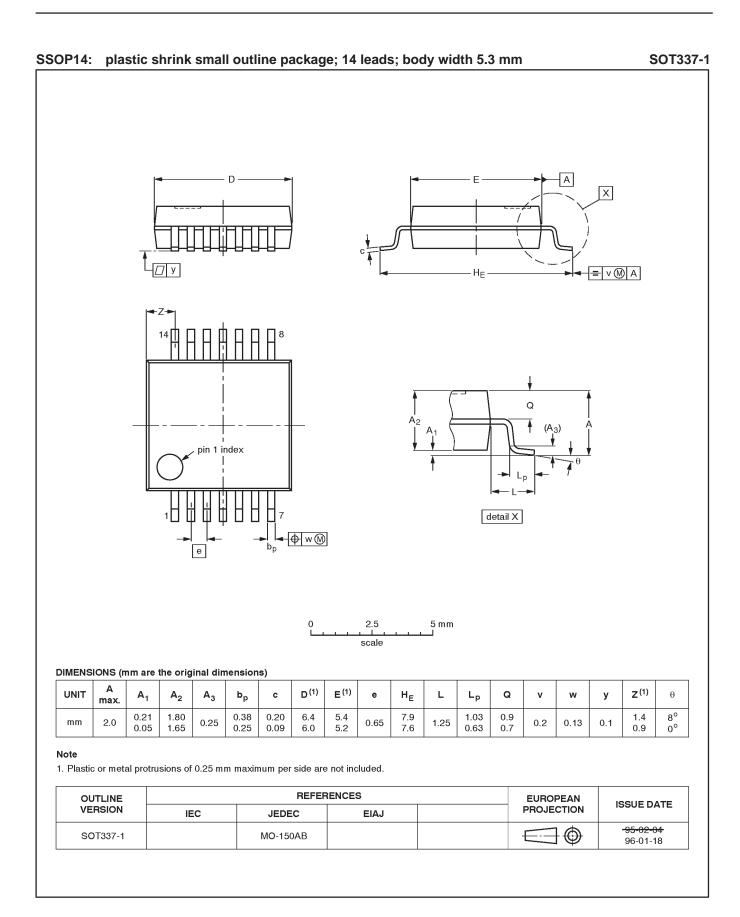
## 74LV14



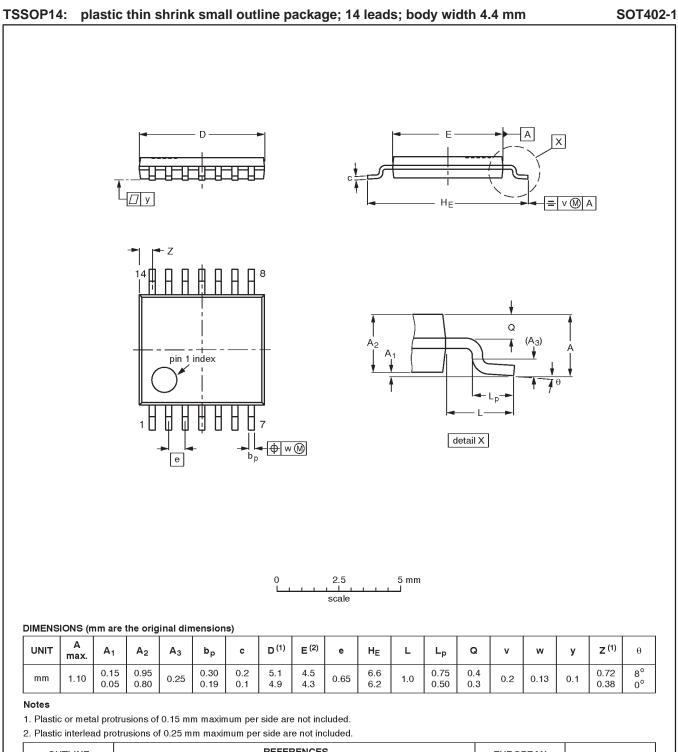
1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT108-1	076E06S	MS-012AB				<del>91-08-13</del> 95-01-23	

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OUTLINE VERSION	REFERENCES				EUROPEAN	ISSUE DATE
	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT402-1		MO-153				<del>-94-07-12</del> 95-04-04

DEFINITIONS						
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